# MSKSEMI 美森科













**ESD** 

T\

TSS

MOV

GDI

PLED

SS8550-MS

**Product specification** 





TRANSISTOR (PNP)

#### **FEATURES**

- High Collector Current
- Complementary to SS8050-MS

#### **Reference News**

PACKAGE OUTLINE		MARKING		
1 2	1. BASE 2. EMITTER 3.COLLECTOR	<b>Y2</b>		
SOT-23				

MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>СВО</sub>	Collector-Base Voltage	-40	V
Vceo	Collector-Emitter Voltage	-25	V
<b>V</b> EBO	Emitter-Base Voltage	-5	V
lc	Collector Current	-1.5	Α
Pc	Collector Power Dissipation	300	mW
R <sub>OJA</sub>	Thermal Resistance From Junction To Ambient	417	°C/W
Tj	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55 ~ <b>+</b> 150	℃

## **ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)**

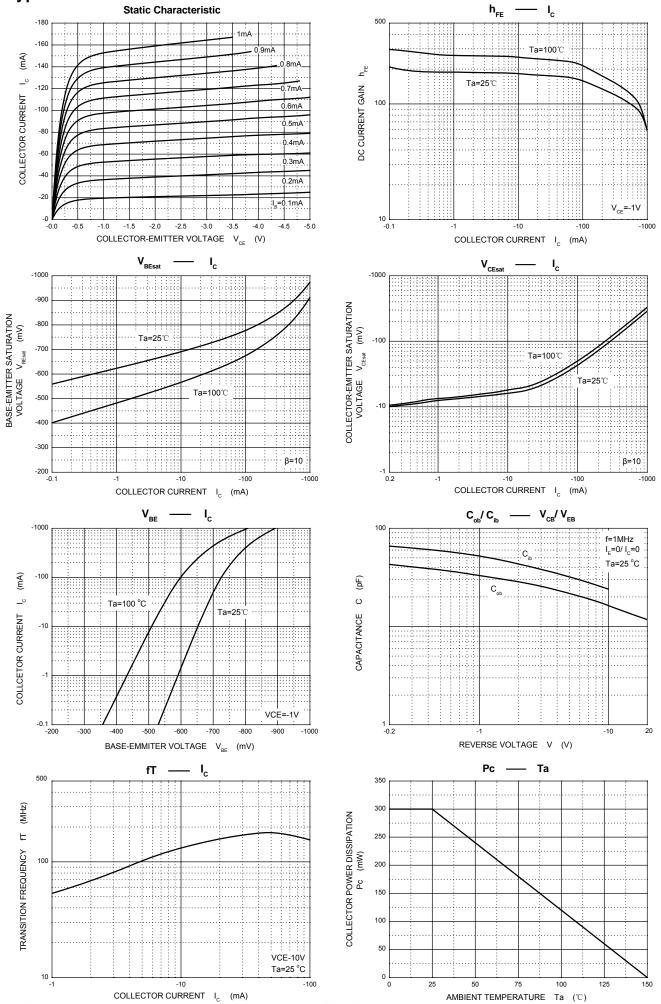
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	lc=-100μA, l∈=0	-40			V
Collector-emitter breakdown voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =-0.1mA, I <sub>B</sub> =0	-25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I <sub>E</sub> =-100μA, I <sub>C</sub> =0	-5			V
Collector cut-off current	Ісво	V <sub>CB</sub> =-40V, I <sub>E</sub> =0			- 100	nA
Collector cut-off current	ICEO	V <sub>CE</sub> =-20V, I <sub>B</sub> =0			- 100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =-5V, I <sub>C</sub> =0			-100	nA
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> =- 1V, I <sub>C</sub> =- 100mA	120		400	
Do current gam	h <sub>FE(2)</sub>	V <sub>CE</sub> =-1V, I <sub>C</sub> =-800mA	40			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-800mA, I <sub>B</sub> =-80mA			-0.5	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =-800mA, I <sub>B</sub> =-80mA			-1.2	V
Base-emitter voltage	$V_{BE}$	V <sub>CE</sub> =-1V, I <sub>C</sub> =-10mA			-1	V
Transition frequency	f⊤	V <sub>CE</sub> =- 10V,I <sub>C</sub> =-50mA , f=30MHz	100			MHz
Collector output capacitance	Cob	V <sub>CB</sub> =- 10V, I <sub>E</sub> =0, f=1MHz			20	pF

# **CLASSIFICATION OF hfe(1)**

RANK	L	Н	J
RANGE	120 –200	200 –350	300 –400

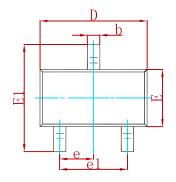


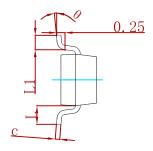
## **Typical Characterisitics**

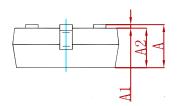




## PACKAGE MECHANICAL DATA

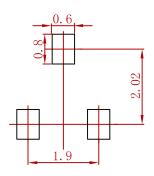






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.03	7 TYP	
e1	1.800	2.000	0.071	0.079	
Ĺ	0.550 REF		0.022	REF	
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

## **Suggested Pad Layout**



#### Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

#### **REEL SPECIFICATION**

P/N	PKG	QTY
SS8550-MS	SOT-23	3000



#### **Attention**

- Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.
- MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all MSKSEMI Semiconductor products described or contained herein.
- Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer'sproducts or equipment.
- MSKSEMI Semiconductor. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with someprobability. It is possiblethat these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits anderror prevention circuitsfor safedesign, redundant design, and structural design.
- In the event that any or all MSKSEMI Semiconductor products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from theauthorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. Whendesigning equipment, referto the "Delivery Specification" for the MSKSEMI Semiconductor productthat you intend to use.

# 单击下面可查看定价,库存,交付和生命周期等信息

>>MSKSEMI (美森科)